

Sample &

Buv





SLVSB18H-MARCH 2012-REVISED AUGUST 2016

# DRV8835 Dual Low-Voltage H-Bridge IC

Technical

Documents

### 1 Features

- Dual-H-Bridge Motor Driver
  - Capable of Driving Two DC Motors or One Stepper Motor
  - Low-MOSFET ON-Resistance: HS + LS 305 m $\Omega$
- 1.5-A Maximum Drive Current Per H-Bridge
- Configure Bridges Parallel for 3-A Drive Current
- Separate Motor and Logic-Supply Pins:
  - 0-V to 11-V Motor-Operating Supply-Voltage
  - 2-V to 7-V Logic Supply-Voltage
- Separate Logic and Motor Power Supply Pins
- Flexible PWM or PHASE/ENABLE Interface
- Low-Power Sleep Mode With 95-nA Maximum Supply Current
- Tiny 2.00-mm × 3.00-mm WSON Package

### 2 Applications

- Battery-Powered:
  - Cameras
  - DSLR Lenses
  - Consumer Products
  - Toys
  - Robotics
  - Medical Devices

### 3 Description

Tools &

Software

The DRV8835 provides an integrated motor driver solution for cameras, consumer products, toys, and other low-voltage or battery-powered motion control applications. The device has two H-bridge drivers, and drives two DC motors or one stepper motor, as well as other devices like solenoids. The output driver block for each consists of N-channel power MOSFETs configured as an H-bridge to drive the motor winding. An internal charge pump generates gate drive voltages.

Support &

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The DRV8835 supplies up to 1.5-A of output current per H-bridge and operates on a motor power supply voltage from 0 V to 11 V, and a device power supply voltage of 2 V to 7 V.

PHASE/ENABLE and IN/IN interfaces are compatible with industry-standard devices.

Internal shutdown functions are provided for overcurrent protection, short circuit protection, undervoltage lockout, and overtemperature.

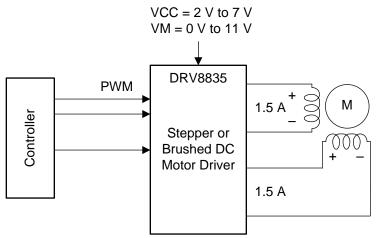
The DRV8835 is packaged in a tiny 12-pin WSON package (Eco-friendly: RoHS and no Sb/Br).

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE   | BODY SIZE (NOM)   |
|-------------|-----------|-------------------|
| DRV8835     | WSON (12) | 2.00 mm × 3.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### **Simplified Schematic**



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### **4** Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Cł | hanges from Revision G (May 2016) to Revision H  | Page |
|----|--|------|
| •  | Changed the value of the capacitor on the VM pin from 10 µF to 0.1 µF in the Parallel Mode Connections figure                | 12   |
| •  | Added one capacitor to the VM pin and updated the value of the existing capacitor on the VM pin in the <i>Layout Example</i> | 15   |
| •  | Deleted references to TI's PowerPAD package and updated it with thermal pad where applicable                                 | 16   |
| •  | Added the Receiving Notification of Documentation Updates section  | 17   |
| Cł | hanges from Revision F (April 2016) to Revision G  | Page |
| •  | Changed the Layout Guidelines to clarify the guidelines for the VM pin   | 15   |
| Cł | hanges from Revision E (December 2015) to Revision F   | Page |
| •  | Deleted nFAULT from the Simplified Schematic in the Description section  | 1    |
| Cł | hanges from Revision D (January 2014) to Revision E  | Page |

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| C | hanges from Revision C (September 2013) to Revision D                        | Page |
|---|--|------|
| • | Changed Features bullet  | 1    |
| • | Changed motor supply voltage range in Description section                    | 1    |
| • | Changed Motor power supply voltage range in Recommended Operating Conditions | 5    |
| • | Added tock and toket parameters to Electrical Characteristics                | 6    |
| • | Added paragraph to Power Supplies and Input Pins section                     | 14   |

**EXAS** NSTRUMENTS

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### 5 Pin Configuration and Functions

| VM<br>AOUT1<br>AOUT2<br>BOUT1<br>BOUT2<br>GND<br>GND<br>Freman<br>GND<br>Freman<br>BOUT2<br>GND<br>Freman<br>BOUT2<br>GND<br>Freman<br>BOUT2<br>GND<br>Freman<br>BOUT2<br>BOUT1<br>Freman<br>BOUT2<br>BOUT1<br>BOUT2<br>BOUT2<br>BOUT1<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOUT2<br>BOU |       |                    |                               |   |  |  |
|--|-------|--------------------|-------------------------------|---|--|--|
| PIN  |       | I/O <sup>(1)</sup> | DESCRIPTION                   | EXTERNAL COMPONENTS OR  |  |  |
| NAME   | NO.   | 1/0(1/             | DESCRIPTION                   | CONNECTIONS   |  |  |
| POWER AND G  | ROUND |                    |                               |   |  |  |
| GND, Thermal<br>pad  | 6     | —                  | Device ground                 |   |  |  |
| VM   | 1     | —                  | Motor supply                  | Bypass to GND with a 0.1-µF (minimum) ceramic capacitor   |  |  |
| VCC  | 12    | _                  | Device supply                 | Bypass to GND with a 0.1-µF (minimum) ceramic capacitor   |  |  |
| CONTROL  |       |                    |                               |   |  |  |
| MODE   | 11    | I                  | Input mode select             | Logic low selects IN/IN mode<br>Logic high selects PH/EN mode<br>Internal pulldown resistor                       |  |  |
| AIN1/APHASE  | 10    | I                  | Bridge A input 1/PHASE input  | IN/IN mode: Logic high sets AOUT1 high<br>PH/EN mode: Sets direction of H-bridge A<br>Internal pulldown resistor  |  |  |
| AIN2/AENBL   | 9     | I                  | Bridge A input 2/ENABLE input | IN/IN mode: Logic high sets AOUT2 high<br>PH/EN mode: Logic high enables H-bridge A<br>Internal pulldown resistor |  |  |
| BIN1/BPHASE  | 8     | Ι                  | Bridge B input 1/PHASE input  | IN/IN mode: Logic high sets BOUT1 high<br>PH/EN mode: Sets direction of H-bridge B<br>Internal pulldown resistor  |  |  |
| BIN2/BENBL   | 7     | I                  | Bridge B input 2/ENABLE input | IN/IN mode: Logic high sets BOUT2 high<br>PH/EN mode: Logic high enables H-bridge B<br>Internal pulldown resistor |  |  |
| OUTPUT   | · · · |                    |                               |   |  |  |
| AOUT1  | 2     | 0                  | Bridge A output 1             | Connect to mater winding A  |  |  |
| AOUT2  | 3     | 0                  | Bridge A output 2             | Connect to motor winding A  |  |  |
| BOUT1  | 4     | 0                  | Bridge B output 1             | Connect to motor winding B  |  |  |
| BOUT2  | 5     | 0                  | Bridge B output 2             |   |  |  |

**DSS Package** 12-Pin WSON With Exposed Thermal Pad Top View

(1) Directions: I = input, O = output

4 Submit Documentation Feedback



### 6 Specifications

### 6.1 Absolute Maximum Ratings

See  $^{(1)(2)}$ 

|                  |   | MIN    | MAX          | UNIT |
|------------------|---|--------|--------------|------|
|                  | Power supply voltage, VM  | -0.3   | 12           | V    |
|                  | Power supply voltage, VCC   | -0.3   | 7            | V    |
|                  | Digital input pin voltage   | -0.5   | VCC + 0.5    | V    |
|                  | Peak motor drive output current                                   | Intern | ally limited | А    |
|                  | Continuous motor drive output current per H-bridge <sup>(3)</sup> | -1.5   | 1.5          | А    |
| TJ               | Operating junction temperature                                    | -40    | 150          | °C   |
| T <sub>stg</sub> | Storage temperature   | -60    | 150          | °C   |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

(3) Power dissipation and thermal limits must be observed.

### 6.2 ESD Ratings

|                    |               |  | VALUE | UNIT |
|--------------------|---------------|--|-------|------|
| V                  | Electrostatic | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | M    |
| V <sub>(ESD)</sub> | discharge     | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1500 | v    |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

 $T_A = 25^{\circ}C$  (unless otherwise noted)

|                  |  | MIN | NOM MAX         | UNIT |
|------------------|--|-----|-----------------|------|
| V <sub>CC</sub>  | Device power supply voltage            | 2   | 7               | V    |
| V <sub>M</sub>   | Motor power supply voltage             | 0   | 11              | V    |
| V <sub>IN</sub>  | Logic level input voltage              | 0   | V <sub>CC</sub> | V    |
| I <sub>OUT</sub> | H-bridge output current <sup>(1)</sup> | 0   | 1.5             | А    |
| $f_{PWM}$        | Externally applied PWM frequency       | 0   | 250             | kHz  |

(1) Power dissipation and thermal limits must be observed.

### 6.4 Thermal Information

|                       |  | DRV8835    |      |
|-----------------------|--|------------|------|
|                       | THERMAL METRIC <sup>(1)</sup>                | DSS (WSON) | UNIT |
|                       |  | 12 PINS    |      |
| $R_{\thetaJA}$        | Junction-to-ambient thermal resistance       | 50.4       | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance    | 58         | °C/W |
| $R_{\theta JB}$       | Junction-to-board thermal resistance         | 19.9       | °C/W |
| ΨJT                   | Junction-to-top characterization parameter   | 0.9        | °C/W |
| ΨЈВ                   | Junction-to-board characterization parameter | 20         | °C/W |
| R <sub>0JC(bot)</sub> | Junction-to-case (bottom) thermal resistance | 6.9        | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

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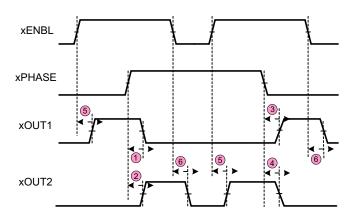
### 6.5 Electrical Characteristics

 $T_{\text{A}}$  = 25°C,  $V_{\text{M}}$  = 5 V,  $V_{\text{CC}}$  = 3 V (unless otherwise noted)

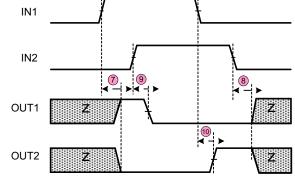
|                     | PARAMETER                         | TEST CONDITIONS  | MIN                 | TYP | MAX                 | UNIT  |  |
|---------------------|-----------------------------------|--|---------------------|-----|---------------------|-------|--|
| POWER S             | SUPPLY                            |  | 1                   |     | H                   |       |  |
|                     | \/M energing ourphy ourrent       | No PWM, no load  |                     | 85  | 200                 |       |  |
| I <sub>VM</sub>     | VM operating supply current       | 50 kHz PWM, no load  |                     | 650 | 2000                | μA    |  |
|                     |                                   | $V_{M}$ = 2 V, $V_{CC}$ = 0 V, all inputs 0 V                                |                     | 5   |                     |       |  |
| I <sub>VMQ</sub>    | VM sleep mode supply current      | $V_{M} = 5 \text{ V}, V_{CC} = 0 \text{ V}, \text{ all inputs } 0 \text{ V}$ |                     | 10  | 95                  | nA    |  |
| I <sub>VCC</sub>    | VCC operating supply current      |  |                     | 450 | 2000                | μA    |  |
| V                   | VCC undervoltage lockout          | V <sub>CC</sub> rising   |                     |     | 2                   | V     |  |
| V <sub>UVLO</sub>   | voltage                           | V <sub>CC</sub> falling  |                     |     | 1.9                 | v     |  |
| LOGIC-LE            | EVEL INPUTS                       |  |                     |     |                     |       |  |
| V <sub>IL</sub>     | Input low voltage                 |  |                     |     | $0.3 \times V_{CC}$ | V     |  |
| V <sub>IH</sub>     | Input high voltage                |  | $0.5 \times V_{CC}$ |     |                     | V     |  |
| IIL                 | Input low current                 | V <sub>IN</sub> = 0  | -5                  |     | 5                   | μA    |  |
| I <sub>IH</sub>     | Input high current                | V <sub>IN</sub> = 3.3 V  |                     |     | 50                  | μA    |  |
| R <sub>PD</sub>     | Pulldown resistance               |  |                     | 100 |                     | kΩ    |  |
| H-BRIDGI            | E FETS                            |  |                     |     |                     |       |  |
| Р                   | HS + LS FET on resistance         | $V_{CC}$ = 3 V, $V_{M}$ = 3 V, I $_{O}$ = 800 mA, $T_{J}$ = 25°C             |                     | 370 | 420                 | mΩ    |  |
| R <sub>DS(ON)</sub> | HS + LS FET OIL TESISIAILLE       | $V_{CC}$ = 5 V, $V_{M}$ = 5 V, I $_{O}$ = 800 mA, $T_{J}$ = 25°C             |                     | 305 | 355                 | 11122 |  |
| I <sub>OFF</sub>    | OFF-state leakage current         |  |                     |     | ±200                | nA    |  |
| PROTECT             | TION CIRCUITS                     | ·  |                     |     |                     |       |  |
| I <sub>OCP</sub>    | Overcurrent protection trip level |  | 1.6                 |     | 3.5                 | А     |  |
| t <sub>DEG</sub>    | Overcurrent de-glitch time        |  |                     | 1   |                     | μs    |  |
| t <sub>OCR</sub>    | Overcurrent protection retry time |  |                     | 1   |                     | ms    |  |
| t <sub>DEAD</sub>   | Output dead time                  |  |                     | 100 |                     | ns    |  |
| t <sub>TSD</sub>    | Thermal shutdown temperature      | Die temperature  | 150                 | 160 | 180                 | °C    |  |

### 6.6 Timing Requirements

| $T_A = 25^{\circ}C, V_M = 5 V, V_{CC} = 3 V, R_L = 20 \Omega$ |                 |                                       |     |     |      |  |
|---|-----------------|---------------------------------------|-----|-----|------|--|
| NO.   |                 |                                       | MIN | MAX | UNIT |  |
| 1   | t <sub>1</sub>  | Delay time, xPHASE high to xOUT1 low  |     | 300 | ns   |  |
| 2   | t <sub>2</sub>  | Delay time, xPHASE high to xOUT2 high |     | 200 | ns   |  |
| 3   | t <sub>3</sub>  | Delay time, xPHASE low to xOUT1 high  |     | 200 | ns   |  |
| 4   | t <sub>4</sub>  | Delay time, xPHASE low to xOUT2 low   |     | 300 | ns   |  |
| 5   | t <sub>5</sub>  | Delay time, xENBL high to xOUTx high  |     | 200 | ns   |  |
| 6   | t <sub>6</sub>  | Delay time, xENBL high to xOUTx low   |     | 300 | ns   |  |
| 7   | t <sub>7</sub>  | Output enable time                    |     | 300 | ns   |  |
| 8   | t <sub>8</sub>  | Output disable time                   |     | 300 | ns   |  |
| 9   | t <sub>9</sub>  | Delay time, xINx high to xOUTx high   |     | 160 | ns   |  |
| 10  | t <sub>10</sub> | Delay time, xINx low to xOUTx low     |     | 160 | ns   |  |
| 11  | t <sub>R</sub>  | Output rise time                      | 30  | 188 | ns   |  |
| 12  | t <sub>F</sub>  | Output fall time                      | 30  | 188 | ns   |  |



PHASE/ENBL mode





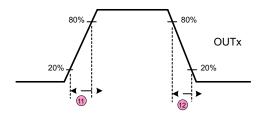


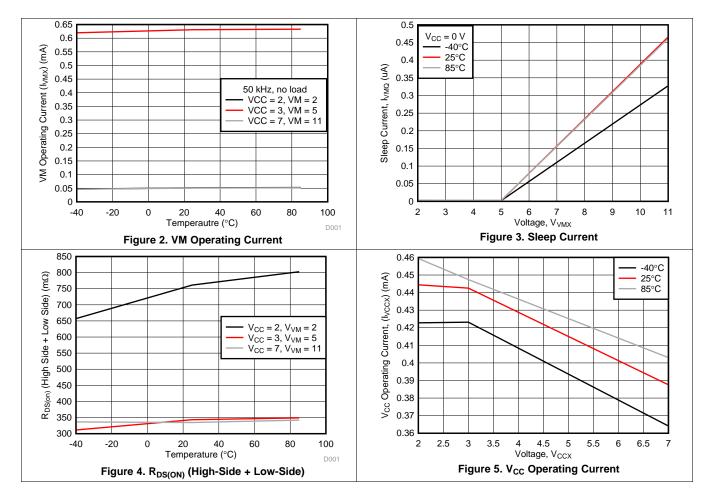
Figure 1. Timing Requirements

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### 6.7 Typical Characteristics





### 7 Detailed Description

### 7.1 Overview

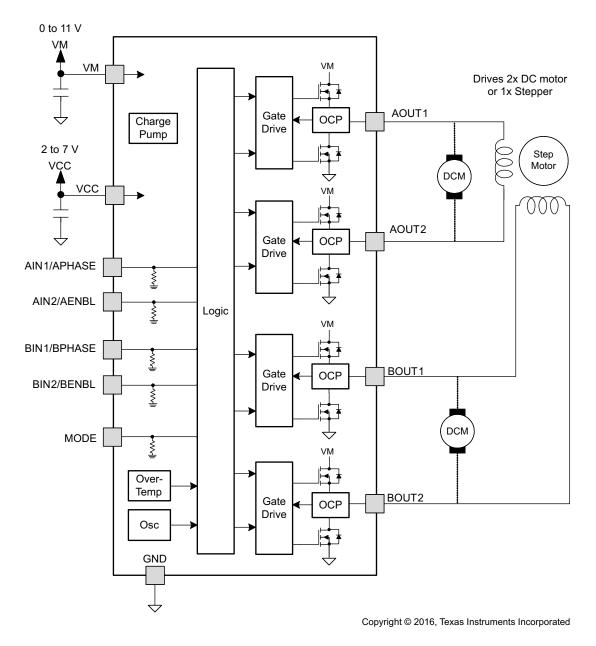
The DRV8835 is an integrated motor-driver solution used for brushed motor control. The device integrates two H-bridges, and drives two DC motor or one stepper motor. The output driver block for each H-bridge consists of N-channel power MOSFETs. An internal charge pump generates the gate drive voltages. Protection features include overcurrent protection, short circuit protection, undervoltage lockout, and overtemperature protection.

The bridges connect in parallel for additional current capability.

The DRV8835 allows separation of the motor voltage and logic voltage if desired. If VM and VCC are less than 7 V, the two voltages can be connected.

The mode pin allow selection of either a PHASE/ENABLE or IN/IN interface.

### 7.2 Functional Block Diagram





#### 7.3 Feature Description

#### 7.3.1 Protection Circuits

The DRV8835 is fully protected against undervoltage, overcurrent, and overtemperature events.

#### 7.3.1.1 Overcurrent Protection (OCP)

An analog current limit circuit on each FET limits the current through the FET by removing the gate drive. If this analog current limit persists for longer than the OCP time, all FETs in the H-bridge disable. After approximately 1 ms, the bridge re-enable automatically.

Overcurrent conditions on both high-side and low-side devices; a short to ground, supply, or across the motor winding result in an overcurrent shutdown.

#### 7.3.1.2 Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all FETs in the H-bridge disable. Operation automatically resumes once the die temperature falls to a safe level.

#### 7.3.1.3 Undervoltage Lockout (UVLO)

If at any time the voltage on the VCC pins falls below the undervoltage lockout threshold voltage, all circuitry in the device disable, and internal logic resets. Operation resumes when VCC rises above the UVLO threshold.

| FAULT                      | CONDITION   | ERROR REPORT | H-BRIDGE | INTERNAL<br>CIRCUITS | RECOVERY         |
|----------------------------|-------------|--------------|----------|----------------------|------------------|
| VCC undervoltage<br>(UVLO) | VCC < VUVLO | None         | Disabled | Disabled             | VCC > VUVLO      |
| Overcurrent (OCP)          | IOUT > IOCP | None         | Disabled | Operating            | tOCR             |
| Thermal Shutdown<br>(TSD)  | TJ > TTSD   | None         | Disabled | Operating            | TJ < TTSD – THYS |

#### Table 1. Device Protection

### 7.4 Device Functional Modes

The DRV8835 is active when the VCC is set to a logic high. When in sleep mode, the H-bridge FETs are disabled (HIGH-Z).

#### **Table 2. Device Operating Modes**

| OPERATING MODE    | CONDITION               | H-BRIDGE  | INTERNAL CIRCUITS |
|-------------------|-------------------------|-----------|-------------------|
| Operating         | nSLEEP high             | Operating | Operating         |
| Sleep mode        | nSLEEP low              | Disabled  | Disabled          |
| Fault encountered | Any fault condition met | Disabled  | See Table 1       |

#### 7.4.1 Bridge Control

Two control modes are available in the DRV8835: IN/IN mode, and PHASE/ENABLE mode. IN/IN mode is selected if the MODE pin is driven low or left unconnected; PHASE/ENABLE mode is selected if the MODE pin is driven to logic high. Table 3 and Table 4 show the logic for these modes.

| MODE | xIN1 | xIN2 | xOUT1 | xOUT2 | FUNCTION<br>(DC MOTOR) |
|------|------|------|-------|-------|------------------------|
| 0    | 0    | 0    | Z     | Z     | Coast                  |
| 0    | 0    | 1    | L     | Н     | Reverse                |
| 0    | 1    | 0    | Н     | L     | Forward                |
| 0    | 1    | 1    | L     | L     | Brake                  |

#### Table 3. IN/IN Mode

### Table 4. Phase/Enable Mode

| MODE | XENABLE | xPHASE | xOUT1 | xOUT2 | FUNCTION<br>(DC MOTOR) |
|------|---------|--------|-------|-------|------------------------|
| 1    | 0       | Х      | L     | L     | Brake                  |
| 1    | 1       | 1      | L     | Н     | Reverse                |
| 1    | 1       | 0      | Н     | L     | Forward                |

### 7.4.2 Sleep Mode

If the VCC pin reaches 0 V, the DRV8835 enters a low-power sleep mode. In this state all unnecessary internal circuitry powers down. For minimum supply current, all inputs should be low (0 V) during sleep mode.

### 8 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 8.1 Application Information

From Controller

LOW = IN/IN; HIGH = PHASE/ENBL

IN1/PHASE .

8.2.1 Design Requirements

Table 5 lists the design requirements.

IN2/ENBL -

The DRV8835 is used in one or two motor control applications. Configure the DRV8835 in parallel to provide double the current to one motor. The following design procedure can be used to configure the DRV8835 in a brushed motor application.

### 8.2 Typical Application

The two H-bridges in the DRV8835 connect in parallel for double the current of a single H-bridge. Figure 6 shows the connections.

0.1 µF

AIN1/APHASE

**BIN1/BPHASE** 

BIN2/BENBL

11 MODE

AIN2/AENBL

10

9

8

7

VCC

5

Š≥

Pad

Thermal

GND

ധ

VM

0.1 uF

AOUT1

AOUT2 3

BOUT1

BOUT2

2

Figure 6. Parallel Mode Connections

| Ta | able 5. | Design | Requi | rement | IS |
|----|---------|--------|-------|--------|----|
|    |         |        |       |        |    |

| DESIGN PARAMETER         | REFERENCE          | VALUE |
|--------------------------|--------------------|-------|
| Motor voltage            | VCC                | 4 V   |
| Motor RMS current        | I <sub>RMS</sub>   | 0.3 A |
| Motor startup current    | I <sub>START</sub> | 0.6 A |
| Motor current trip point | I <sub>LIMIT</sub> | 0.5 A |

Product Folder Links: DRV8835

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#### 8.2.2 Detailed Design Procedure

#### 8.2.2.1 Motor Voltage

The appropriate motor voltage depends on the ratings of the motor selected and the desired RPM. A higher voltage spins a brushed DC motor faster with the same PWM duty cycle applied to the power FETs. A higher voltage also increases the rate of current change through the inductive motor windings.

#### 8.2.2.2 Lower-Power Operation

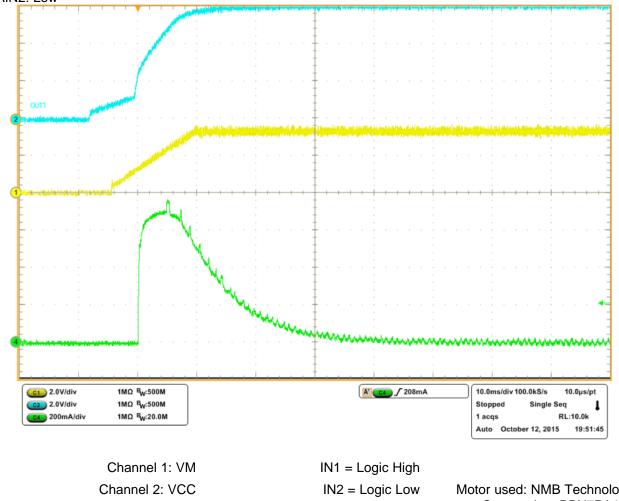
When entering sleep mode, TI recommends setting all inputs as a logic low to minimize system power.

#### 8.2.3 Application Curve

The following scope captures motor startup as V<sub>CC</sub> ramps from 0 V to 6 V. Channel 1 is VCC, Channel 2 is VM, and Channel 4 is the motor current of an unloaded motor during startup. The motor used is a NMB Technologies Corporation, PPN7PA12C1. As VCC and VM ramp, the current in the motor increases until the motor speed builds up. The motor current then reduces for normal operation.

Inputs are set as follows:

- Mode: IN/IN
- AIN1: High
- AIN2: Low



Channel 4: Motor current



Motor used: NMB Technologies Corporation, PPN7PA12C1

Submit Documentation Feedback

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### 9 Power Supply Recommendations

### 9.1 Bulk Capacitance

The appropriate local bulk capacitance is an important factor in motor drive system design. More bulk capacitance is generally beneficial, but may increase costs and physical size.

The amount of local capacitance needed depends on a variety of factors, including:

- · The highest current required by the motor system
- The power supply's capacitance and ability to source current
- The amount of parasitic inductance between the power supply and motor system
- The acceptable voltage ripple
- The type of motor used (brushed DC, brushless DC, stepper)
- The motor braking method

### 9.2 Power Supplies and Input Pins

There is a weak pulldown resistor (approximately 100 k $\Omega$ ) to ground on the input pins.

VCC and VM may be applied and removed in any order. When VCC is removed, the device enters a low power state and draws very little current from VM. To minimize current draw, keep the input pins at 0 V during sleep mode.

The VM voltage supply does not have any undervoltage lockout protection (UVLO), so as long as VCC > 1.8 V, the internal device logic remains active. This means that the VM pin voltage may drop to 0 V, however, the load may not be sufficiently driven at low-VM voltages.





### 10 Layout

### **10.1 Layout Guidelines**

The VCC pin should be bypassed to GND using low-ESR ceramic bypass capacitors with a recommended value of 0.1  $\mu$ F rated for VCC. This capacitor should be placed as close to the VCC pin as possible with a thick trace.

The VM pin should be bypassed to GND using low-ESR ceramic bypass capacitors with a recommended value of 0.1  $\mu$ F rated for VM. This capacitor should be placed as close to the VM pin as possible with a thick trace. The VM pin must bypass to ground using an appropriate bulk capacitor. This component can be an electrolytic and should be located close to the DRV8835.

### **10.2 Layout Example**

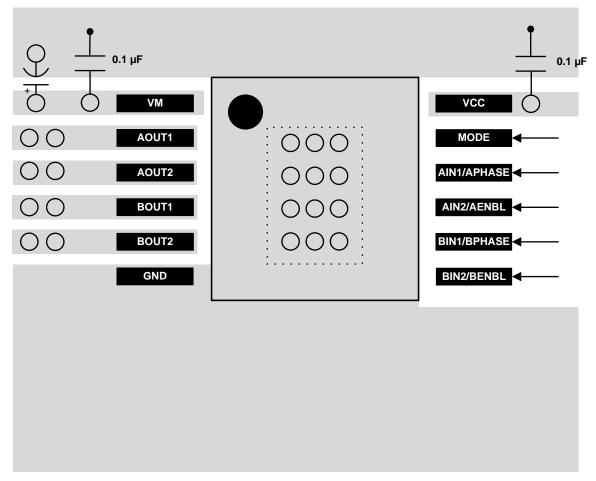


Figure 8. Layout Recommendation

### **10.3 Thermal Considerations**

The DRV8835 has thermal shutdown (TSD) as described above. If the die temperature exceeds approximately 150°C, the device disables until the temperature drops to a safe level.

Any tendency of the device to enter thermal shutdown is an indication of either excessive power dissipation, insufficient heatsinking, or excessively high ambient temperature.

### Thermal Considerations (continued)

### 10.3.1 Power Dissipation

Power dissipation in the DRV8835 is dominated by the power dissipated in the output FET resistance, or  $R_{DS(on)}$ . Average power dissipation when running both H-bridges can be roughly estimated by Equation 1:

 $P_{TOT} = 2 \times R_{DS(ON)} \times (I_{OUT(RMS)})^2$ 

where

P<sub>TOT</sub> is the total power dissipation, R<sub>DS(ON)</sub> is the resistance of the HS plus LS FETs, and I<sub>OUT(RMS)</sub> is the RMS output current being applied to each winding. I<sub>OUT(RMS)</sub> is equal to the approximately 0.7× the full-scale output current setting. The factor of 2 comes from the fact that there are two H-bridges. (1)

The maximum amount of power dissipated in the device is dependent on ambient temperature and heatsinking.

#### NOTE

 $R_{DS(on)}$  increases with temperature, so as the device heats, the power dissipation increases. Consider this increase when sizing the heatsink.

The power dissipation of the DRV8835 is a function of RMS motor current and the resistance of each FET  $(R_{DS(ON)})$ , see Equation 2.

Power  $\approx I_{RMS}2 \times (High-Side R_{DS(on)} + Low-Side R_{DS(on)})$ 

For this example, the ambient temperature is 35°C, and the junction temperature reaches 65°C. At 65°C, the sum of  $R_{DS(on)}$  is about 1  $\Omega$ . With an example motor current of 0.8 A, the dissipated power in the form of heat will be 0.8 A<sup>2</sup> × 1  $\Omega$  = 0.64 W.

The temperature that the DRV8835 reaches depends on the thermal resistance to the air and PCB. It is important to solder the device thermal pad to the PCB ground plane, with vias to the top and bottom board layers, in order dissipate heat into the PCB and reduce the device temperature. In the example used here, the DRV8835 had an effective thermal resistance  $R_{\theta JA}$  of 47°C/W, and as shown in Equation 3.

 $T_J = T_A + (P_D \times R_{\theta JA}) = 35^{\circ}C + (0.64 \text{ W} \times 47^{\circ}C/\text{W}) = 65^{\circ}C$ 

### 10.3.2 Heatsinking

The package uses an exposed pad to remove heat from the device. For proper operation, this pad must thermally connect to copper on the PCB to dissipate heat. On a multi-layer PCB with a ground plane, this can be accomplished by adding a number of vias to connect the thermal pad to the ground plane. On PCBs without internal planes, copper area can be added on either side of the PCB to dissipate heat. If the copper area is on the opposite side of the PCB from the device, thermal vias are used to transfer the heat between top and bottom layers.

For more PCB design details, refer to *QFN/SON PCB Attachment* and *AN-1187 Leadless Leadframe Package* (*LLP*), available at www.ti.com.

In general, the more copper area that is provided, the more power can be dissipated.

(2)

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### **11** Device and Documentation Support

### **11.1 Documentation Support**

#### 11.1.1 Related Documentation

For related documentation see the following:

- AN-1187 Leadless Leadframe Package (LLP) (SNOA401)
- Calculating Motor Driver Power Dissipation (SLVA504)
- DRV8835/DRV8836 Evaluation Module (SLVU694)
- QFN/SON PCB Attachment (SLUA271)
- Understanding Motor Driver Current Ratings (SLVA505)

### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### **11.3 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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#### 11.4 Trademarks

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### 11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



### PACKAGING INFORMATION

| Orderable<br>part number | Status<br>(1) | Material type (2) | Package   Pins  | Package qty   Carrier | <b>RoHS</b><br>(3) | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking<br>(6) |
|--------------------------|---------------|-------------------|-----------------|-----------------------|--------------------|-------------------------------|----------------------------|--------------|---------------------|
|                          |               |                   |                 |                       |                    | (4)                           | (5)                        |              |                     |
| DRV8835DSSR              | Active        | Production        | WSON (DSS)   12 | 3000   LARGE T&R      | Yes                | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 85    | 835                 |

<sup>(1)</sup> **Status:** For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

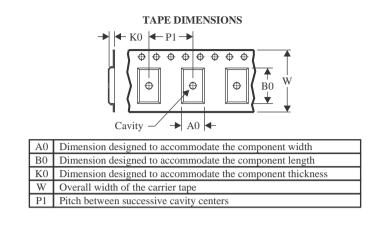
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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nomina | al |
|----------------------------|----|
|----------------------------|----|

| Device      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| DRV8835DSSR | WSON            | DSS                | 12 | 3000 | 180.0                    | 8.4                      | 2.25       | 3.25       | 1.05       | 4.0        | 8.0       | Q1               |



# PACKAGE MATERIALS INFORMATION

9-Aug-2022



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV8835DSSR | WSON         | DSS             | 12   | 3000 | 182.0       | 182.0      | 20.0        |

# **GENERIC PACKAGE VIEW**

# WSON - 0.8 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4209244/D

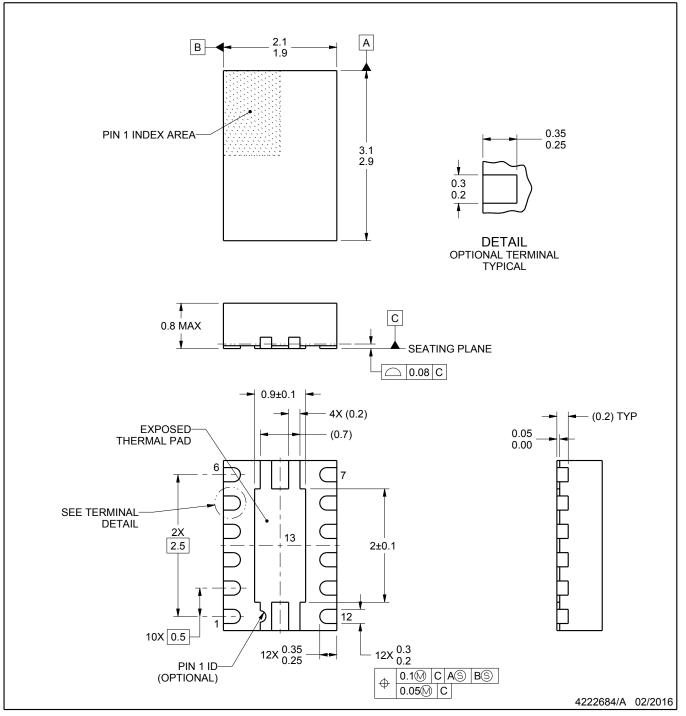
# **DSS0012A**



# **PACKAGE OUTLINE**

### WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

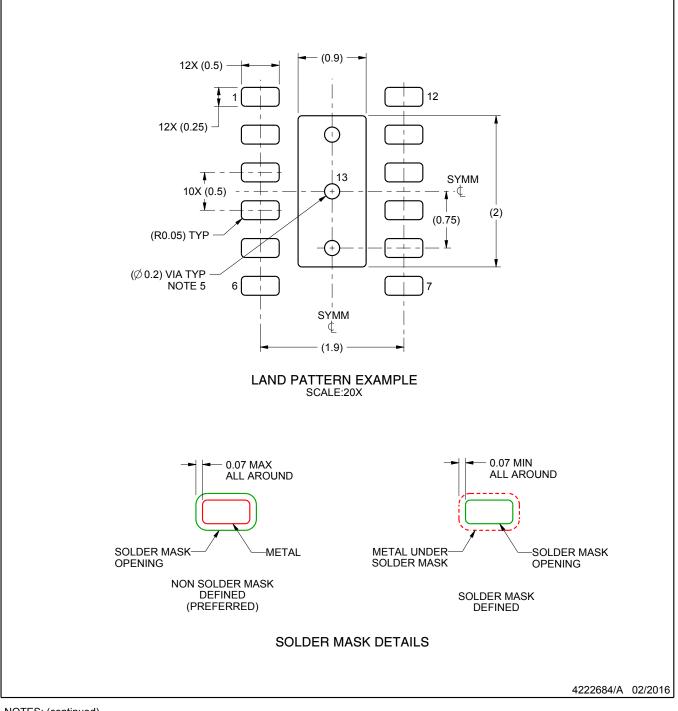


# DSS0012A

# **EXAMPLE BOARD LAYOUT**

### WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown. It is recommended that vias located under solder paste be filled, plugged or tented.

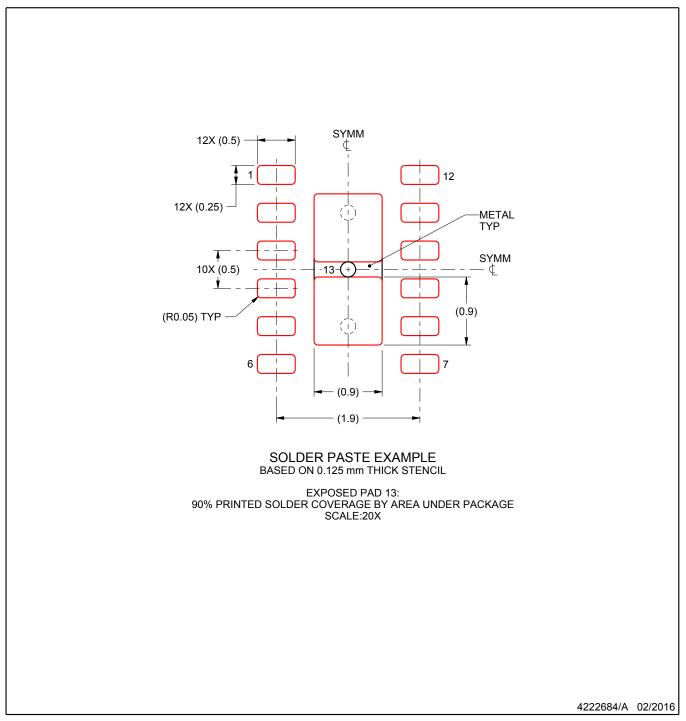


# DSS0012A

# **EXAMPLE STENCIL DESIGN**

### WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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